Enhancing frustrated double ionisation with no electronic correlation in triatomic molecules using counter-rotating two-color circular laser fields

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We demonstrate significant enhancement of frustrated double ionization (FDI) in the two-electron triatomic molecule D$_3^+$ when driven by counter-rotating two-color circular (CRTC) laser fields. We employ a three-dimensional semiclassical model that fully accounts for electron and nuclear motion in strong fields. For different pairs of wavelengths, we compute the probabilities of the FDI pathways as a function of the ratio of the two field-strengths. We identify a pathway of FDI that is not present in strongly-driven molecules with linear fields. In this pathway the first ionization step is “frustrated” and electronic correlation is essentially absent. This pathway is responsible for enhancing FDI with CRTC fields. We also employ a simple model that predicts many of the main features of the probabilities of the FDI pathways as a function of the ratio of the two field-strengths.

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Formation of highly excited Rydberg states, during the interaction of atoms and molecules with laser fields, is a fundamental problem with a wide range of applications. Rydberg states underlie, for instance, acceleration of neutral particles, formation of molecules via long-range interactions, and inversion of N$_2$ in free-space air lasing. Recently, the formation of Rydberg states in weakly-driven H$_2$ was accounted for by electron-nuclear correlated multiphoton resonant excitation. For H$_2$ driven by intense infrared laser fields (strongly-driven), this latter process was shown to merge with frustrated double ionization (FDI). FDI accounts for the formation of Rydberg fragments in strongly-driven two-electron molecules. In frustrated ionization an electron first tunnel ionizes in the driving laser field. Then, due to the electric field, this electron is recaptured by the parent ion in a Rydberg state. In FDI an electron escapes while another one occupies a Rydberg state at the end of the laser pulse.

For linear laser fields, FDI is a major process during the breakup of strongly-driven molecules, accounting for roughly 10% of all ionization events. Hence, FDI has been the focus of intense experimental studies in the context of H$_2$, D$_2$, and of the two-electron triatomic molecules D$_3^+$ and H$_3^+$. For strongly-driven two-electron diatomic and triatomic molecules, FDI proceeds via two pathways. One electron tunnel ionizes early on (first step), while the remaining bound electron does so later in time (second step). If the second (first) ionization step is “frustrated”, we label the FDI pathway as FSIS (FFIS), previously referred to as pathway A (B). Electron-electron correlation, underlying pathway FFIS, can be controlled with orthogonally polarised two-color linear (OTC) laser fields.

Here, we show that counter-rotating two-color circular (CRTC) laser fields are a powerful tool for controlling FDI in strongly-driven molecules. CRTC fields have attracted a lot of interest due to their applicability to the production, via high harmonic generation, of circular pulses with extreme-ultraviolet to soft-x-ray wavelengths. This capability of CRTC fields has been demonstrated in groundbreaking experiments. The latter open the way to investigate chirality-sensitive light-matter interactions and probe properties of magnetic structures. Moreover, the relative intensity of the two colors in CRTC fields has been used to control nonsequential double ionization in driven atoms.

We demonstrate that CRTC fields significantly enhance FDI in D$_3^+$, compared to OTC fields. Pathway FFIS accounts for the increase in the formation of Rydberg fragments. We find that electron-electron correlation does not necessarily underly pathway FFIS. This is unlike our findings with linear fields. If anything, a significant enhancement of pathway FFIS coincides, roughly, with an absence of electronic correlation. Hence, pathway FFIS is a more general route to FDI than previously recognized. We find that pathway FSIS and FFIS with or without electronic correlation, prevail at different ratios of the field-strengths of CRTC. Thus, appropriate tuning of the field strengths results in controlling the prevalent route to FDI. Importantly, we employ a simple model that successfully accounts for many of the main features of FDI and its pathways, where the latter are obtained with a full-scale computation.

We focus on FDI in D$_3^+$ driven by CRTC fields with wavelengths $\lambda_1 = 800$ nm and $\lambda_2 = 400$ nm. We achieve maximum enhancement of FDI when the ratio of the field strengths is $\xi_1 = E_2/E_1 = 4$. FDI accounts roughly for 20% of all ionization events. We develop a simple model to explain main features of the full-scale-computed probabilities of the FDI pathways as a function of $\xi_1$. Further below, we show that this model predicts main features of FDI for a range of pairs of wavelengths. We set $E_1 + E_2 = 0.08$ a.u., intensity of $2.25 \times 10^{14}$ W/cm$^2$, keeping roughly constant the ionisation probability. In what follows, we employ atomic units unless otherwise stated.

We employ a three-dimensional (3D) semiclassical
model for our full-scale computations \[13, 15\]. We choose an initial state of \(D^+_3\) that is accessed experimentally via the reaction \(D_2 + D^+_3 \rightarrow D^+_3 + D\) \[8, 10\]. This state consists of a superposition of vibrational states \(v = 112\) with triangular-shape \[10, 32\]. For each \(v\) level, we assume that most of the \(D^+_3\) ionization occurs at the outer classical turning point \[33, 34\]. The latter varies from 2.04 a.u. (\(v = 1\)) to 2.92 a.u. (\(v = 12\) \[32, 33\]. We initialise the three nuclei at rest, since an initial predissociation does not significantly alter the ionization dynamics \[15\]. Moreover, the strength of the combined field is within the below-the-barrier ionization regime. Hence, one electron (electron 1) tunnel ionizes at time \(t_0\) through the field-lowered Coulomb potential. It does so with a rate given by a quantum mechanical formula \[38\]. The exit point is taken along the direction of the field \[17\]. The electron momentum parallel to the combined field is equal to zero, while a Gaussian distribution describes the transverse one \[37\]. The initially bound electron (electron 2) is described by a microcanonical distribution \[38\].

We use CRTC fields of the form

\[
\begin{align*}
\mathcal{E}(t) &= \exp \left[ -2 \ln 2 \left( \frac{t}{\tau} \right)^2 \right] \\
|E_1(t)\vec{x} \cos \omega_1 t + \vec{z} \sin \omega_1 t| + |E_2(t)\vec{x} \cos \omega_2 t - \vec{z} \sin \omega_2 t|,
\end{align*}
\]

where \(\tau = 40\) fs is the full width at maximum of the pulse duration in intensity. For the ratios \(\varepsilon_1 = E_2/E_1\) and \(\varepsilon_2 = \lambda_1/\lambda_2 = \omega_2/\omega_1\) considered here, the combined laser field has \(\varepsilon_2 = 1\) lobes, with one of them being along the \(x\)-axis, see Fig. 1. Once the tunnel-ionisation time \(t_0\) is selected randomly in the time interval \([-2\tau, 2\tau]\), we specify the initial conditions. Then, employing the Hamiltonian of the strongly driven five-body system, we propagate classically the position and momentum of the electrons and nuclei. All Coulomb forces and the interaction of each electron and nucleus with the CRTC fields are fully accounted for with no approximation. We also fully account for the Coulomb singularities \[15\]. The motion of the electrons and the nuclei are treated on an equal footing, accounting for the interwind electron-nuclear dynamics \[5, 39\]. During propagation, we allow each electron to tunnel with a quantum-mechanical probability given by the Wentzel-Kramers-Brillouin approximation \[12, 16\]. We thus accurately account for enhanced ionization (EI) \[40, 41\]. In EI, at a critical distance of the nuclei, a double-potential well is formed such that it is easier for an electron bound to the higher potential well to tunnel to the lower potential well and then ionize.

In FDI of \(D^+_3\), the final fragments are a neutral excited fragment \(D^*\), two \(D^+\) ions, and one escaping electron. In the neutral excited fragment \(D^*\) the electron transitions to a Rydberg state with quantum number \(n > 1\). Here, we find that the Rydberg state with \(n \approx 10\) is the most probable to form during FDI with CRTC fields. In pathway FSIS, electron 1 tunnel ionizes and escapes early on. Electron 2 gains energy from an EI-like process and tunnel ionizes. However, it does not have enough drift energy to escape when CRTC is turned off, and occupies a Rydberg state, \(D^*\). In pathway FFIS, electron 1 tunnel ionizes and quivers in the laser field. Electron 2 tunnel ionizes after a few periods of the laser field. Electron 2 gains energy from an EI-like process. Depending on \(\varepsilon_1\) and \(\varepsilon_2\), electron 2 can, in addition, gain energy from the returning electron 1 via electron-electron correlation. When the laser field is turned off, electron 1 does not have enough energy to escape and remains bound in a Rydberg state. In studies with linear laser fields, we found that electronic correlation underlies pathway FFIS \[12, 15\]. For CRTC fields, we show that electronic correlation underlies pathway FFIS only for certain \(\varepsilon_1\) values.

We compute the FDI probability using

\[
P_{\text{FDI}}(\varepsilon_1, \varepsilon_2) = \frac{\sum_{\nu, i} P_\nu \Gamma(\nu, i, \varepsilon_1, \varepsilon_2) P_{\text{FDI}}^{\nu}(\nu, i, \varepsilon_1, \varepsilon_2)}{\sum_{\nu, i} P_\nu \Gamma(\nu, i, \varepsilon_1, \varepsilon_2)},
\]

where \(i\) denotes the different orientations of the molecule. \(\Gamma(\nu, i, \varepsilon_1, \varepsilon_2)\) is given by

\[
\Gamma(\nu, i, \varepsilon_1, \varepsilon_2) = \int_{t_{\text{min}}}^{t_{\nu}} \Gamma(t_0, \nu, i, \varepsilon_1, \varepsilon_2) \, dt_0,
\]

where the integration is over the duration of CRTC and \(\Gamma(t_0, \nu, i, \varepsilon_1, \varepsilon_2)\) is the ionization rate. \(\Gamma(\nu, i, \varepsilon_1, \varepsilon_2)\) remains roughly the same, for constant \(\varepsilon_1 + \varepsilon_2\). The percentage of the vibrational state \(\nu\) in the initial state of \(D^+_3\) is denoted by \(P_\nu\). The probability \(P_{\text{FDI}}^{\nu}(\nu, i, \varepsilon_1, \varepsilon_2)\) is the number of FDI events out of all initiated classical trajectories. The computations involved are challenging. Hence, we approximate Eq. (2) using the \(\nu = 8\) state, which we find to contribute the most in the sum in Eq. (2). Moreover, we consider two planar alignments,
with one side of the molecular triangle being either parallel or perpendicular to the x-lobe, the latter is shown in Fig. 2(a). We find that the change of $P_{FDI}$ with $\epsilon_1$ is roughly the same for both orientations. Thus, we choose the perpendicular orientation to compute all our results. For CRTC fields with $\lambda_1 = 800$ nm and $\lambda_2 = 400$ nm, the dependence on $\epsilon_1$ of the total FDI probability and of the FSIS and FFIS probabilities have several interesting features, see Fig. 2(a1). The FDI probability reaches 17% at $\epsilon_1 \approx 4$. This is twice the FDI probability we computed previously for both a single linear pulse of 800 nm [13] and an OTC pulse with 800 nm and 400 nm [14]. Thus, CRTC fields significantly enhance FDI. In studies with linear fields, pathways FSIS and FFIS contribute to FDI roughly the same [13, 14]. In contrast, for CRTC fields, the FFIS probability is roughly twice the FSIS probability for $\epsilon_1 \approx 4$, see Fig. 2(a1).

Another striking feature of the change of the FDI probability with $\epsilon_1$, is the “plateau” the FFIS probability exhibits around $\epsilon_1 = 2$. For smaller $\epsilon_1$ and larger values up to $\epsilon_{max}^{FSIS}$, the FFIS probability increases sharply. The value $\epsilon_{max}^{FSIS}$ ($\epsilon_{max}^{FFIS}$) corresponds to the peak of the FSIS (FFIS) probability. A “plateau” suggests a different mechanism underlying pathway FFIS at $\epsilon_1 = 2$ compared to other $\epsilon_1$ values. Indeed, we find that electronic correlation plays a major role in pathway FFIS mostly around $\epsilon_1 = 2$. To show this, we also compute the FDI probabilities with electron-electron correlation turned off in our 3D semiclassical model. Comparing the FFIS probabilities with and without electronic correlation, we find that the FDI probability reduces by more than 50% around $\epsilon_1 = 2$, see Fig. 2(a1). However, the effect of electron-electron correlation is small on the FFIS probability around $\epsilon_{max}^{FFIS}$. The FSIS probability remains roughly the same (not shown), as is the case for linear fields [13, 14]. Moreover, compared to the FSIS probability, FFIS peaks at a higher $\epsilon_1$ and reduces at a much faster rate for large $\epsilon_1$, see Fig. 2(a1).

To understand these features of the change of the FDI probabilities with $\epsilon_1$, we employ a simple model. This model entails an estimate of the final electron momentum in the presence of the CRTC fields, defined in Eq. 1.

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Using these assumptions and setting the field envelope equal to 1, we solve the classical equations of motion to obtain

$$P_{F}(t) = A(t) - A(t_1)$$

$$r(t) = r(t_1) + \int_{t_1}^{t} A(t')dt' - \int_{t_1}^{t} A(t_1)dt'$$

We find that an electron returns to its initial position at the time of ionization, i.e. $r(t_1) = r(t_1)$ at times $\omega t = 2(n + 1)\pi$ if $\omega t_1 = 2n\pi$ and $\epsilon_1 = \epsilon_2$, with $n$ an integer. For these conditions, $p_{F}(t)$ and $p_{F}(t)$ are zero.

Next, we obtain, for each $\epsilon_1$, the distribution of the magnitude of the final electron momentum $p_{F,i}$. Namely, we compute $|A(t_i)|$ in the time interval $t_i \in [0, T)$, with...
T the period of the CRTC fields. An electron tunnel ionizes with different rates at different times. To account for this, we take the tunnel ionization and ionization times to be the same. This assumption is more accurate for electron 1. For simplicity, we assume that electron i ionizes with the atomic quantum tunnelling rate \( \Gamma_{\text{ADK}} \) given by the Ammosov-Delone-Krainov (ADK) formula \[46\]. In \( \Gamma_{\text{ADK}} \), we set the ionization energy \( I_p \) equal to the first ionization potential of \( D_3^+ \). We take the effective charge \( Z_{\text{eff}} \) equal to the asymptotic one an electron “sees” when moving away from \( D_3^+ \). Our results are similar for other values of \( I_p \) and \( Z_{\text{eff}} \). Weighting each \( p_{\text{f},i} \) by \( \frac{\Gamma_{\text{ADK}}(t_i)}{\int_0^T \Gamma_{\text{ADK}}(t_j) dt_j} \), we obtain the distribution of \( p_{\text{f},i} \) as a function of \( \epsilon_1 \), shown in Fig. 2(b1).

Below we show that the change of the distribution of \( p_{\text{f},i} \) with \( \epsilon_1 \) accounts for the main features of the FDI probabilities as a function of \( \epsilon_1 \). The distribution of \( p_{\text{f},i} \), for \( 0 < \epsilon_1 < \epsilon_2 \), is narrow and decreases sharply, starting from large values and reaching zero at \( \epsilon_1 = \epsilon_2 \), see Fig. 2(b1). For \( \epsilon_1 > \epsilon_2 \), the distribution of \( p_{\text{f},i} \) is wide and increases at a slower rate than its decrease rate, reaching at \( \epsilon_1 \rightarrow \infty \) smaller values than at \( \epsilon_1 = 0 \). For large \( p_{\text{f},i} \) values, either electron has a high chance of finally escaping at the end of the laser field, i.e. a small chance for FDI. Indeed, the FDI probabilities are decreasing (increasing) when \( \epsilon_1 \) increases (decreasing) with \( \epsilon_1 \) values, as discussed earlier. This is in accord with the “plateau” in the FFIS probability being around \( \epsilon_1 = \epsilon_2 \) for CRTC fields with \( \lambda_1 = 800 \text{ nm} \) and \( \lambda_2 = 400 \text{ nm} \). Hence, for CRTC fields, our findings suggest that electron-electron correlation underlies pathway FFIS mostly when \( p_{\text{f},i} \) has small values. This is corroborated by our previous finding of electron-electron correlation underlying pathway FFIS for linear fields \[13\]-\[14\].

Indeed, for a linear field with \( \epsilon = 0.08 \text{ a.u.} \) and \( \lambda = 800 \text{ nm} \), the simple model we employ yields small \( p_{\text{f},i} \) values.

The simple model described above predicts the change of the FDI probabilities with \( \epsilon_1 \) for a range of pairs of wavelengths of CRTC fields. Indeed, first, using this simple model, we compute the distribution of \( p_{\text{f},i} \) with \( \epsilon_1 \) for \( \lambda_1 = 1200 \text{ nm} \) and \( \lambda_2 = 400 \text{ nm} \), i.e. \( \epsilon_2 = 3 \) (Fig. 2(b2)), for \( \lambda_1 = 1600 \text{ nm} \) and \( \lambda_2 = 400 \text{ nm} \), i.e. \( \epsilon_2 = 4 \) (Fig. 2(b3)), and for \( \lambda_1 = 1600 \text{ nm} \) and \( \lambda_2 = 800 \text{ nm} \), i.e. \( \epsilon_2 = 2 \) (Fig. 2(b4)). Next, for the same parameters, using our full-scale 3D semiclassical model, we compute the probabilities of the total FDI and its pathways in Fig. 2(a2)-(a4). As expected, a comparison of Fig. 2(b2)-(b4) with Fig. 2(b2)-(b4), respectively, reveals that the FSIS probability peaks at \( \epsilon_1 \approx \epsilon_2 \). In addition, electron-electron correlation underlies pathway FFIS mainly at \( \epsilon_1 \approx \epsilon_2 \), as discussed above. This is the case for all pairs of \( \lambda \)'s with small \( p_{\text{f},i} \) around \( \epsilon_1 = \epsilon_2 \), see “plateau” enclosed by the dotted square in Fig. 2(a1)-(a3). This is the case for all pairs of \( \lambda \)'s with small \( p_{\text{f},i} \), see Fig. 2(b1)-(b3). In contrast for \( \lambda_1 = 1600 \text{ nm} \) and \( \lambda_2 = 800 \text{ nm} \), \( p_{\text{f},i} \) is not as small around \( \epsilon_1 = \epsilon_2 \) (Fig. 2(b4)), resulting in electronic correlation having a small effect in FDI probabilities for all \( \epsilon_1 \)s (Fig. 2(a4)). Also, as discussed above, for large \( \epsilon_1 \), the FFIS probability decreases in accord with the increase of \( p_{\text{f},i} \) with \( \epsilon_1 \). Indeed, the rate of decrease of the FFIS probability is higher for \( \lambda_1 = 1600 \text{ nm} \) and \( \lambda_2 = 800 \text{ nm} \) when compared to \( \epsilon_2 = 3 \) and \( \epsilon_2 = 4 \) with \( \lambda_2 = 400 \text{ nm} \), since \( p_{\text{f},i} \) increases at a faster rate in the former case.

Which pair of \( \lambda \)'s is best suited to infer experimentally electronic correlation in FDI in \( D_3^+ \) driven by CRTC fields? One expects to be the pair of \( \lambda \)'s resulting in \( p_{\text{f},i} \) being roughly zero over a wider region of \( \epsilon_1 \). This condition is best satisfied for \( \lambda_1 = 1600 \text{ nm} \) and \( \lambda_2 = 400 \text{ nm} \), see Fig. 2(b3), giving rise to a wider, and thus more visible, “plateau” in the FFIS probability, see Fig. 2(a3).

Unlike pathway FSIS, the \( \epsilon_1 \) value where the FFIS probability peaks, \( \epsilon_{\text{max}} \), is not predicted by the simple model. Analysis of the trajectories obtained with our full-scale computations assists in understanding \( \epsilon_{\text{max}} \). We find that electron 2 ionizes at times \( t_i \) when the vector potential \(|A(t_i)|\) is maximum. However, tunnel
ionization occurs mostly at times when the laser field is maximum. A comparison of the FFIS probabilities with and without electronic correlation (Fig. 2(a)) shows that electronic correlation has a small effect on FDI at \( \varepsilon_1 \) around \( \varepsilon_{\text{max}}^{\text{FFIS}} \). Hence, we expect the FFIS probability to be maximum at \( \varepsilon_1 \) values where the extrema of \(|\mathcal{A}|^2 = 0.08 \) a.u. and \( \lambda = 800 \) nm, these two conditions that lead to pathway FFIS with no electronic correlation are not satisfied to the extent they are for CRTC fields with \( \lambda_2 = 400 \) nm. That is, \( g \approx 0.3 \) and \( p_{\text{F1}} \) is small with values close to the values of \( p_{\text{F1}} \) in CRTC fields at \( \varepsilon_1 = \varepsilon_2 \), thus favouring pathway FFIS with electronic correlation. As a result, the most probable pathway with CRTC fields, i.e. FFIS with no electronic correlation, contributes little to FDI with linear fields.

In conclusion, we have shown that strong driving of two-electron triatomic molecules with counter-rotating two-color circular laser fields significantly enhances FDI compared to linear fields. For each pair of wavelengths, by suitably tuning the ratio of the two field-strengths, we achieve significant enhancement of pathway FFIS with electronic correlation being roughly absent. This pathway has not been previously identified. Pathway FFIS with electronic correlation, identified in our studies with linear fields [12–14], still prevail at different ratios of the field strengths. Its main trace is a “plateau” in the FDI probability as a function of the ratio of the two field-strengths. Moreover, we have developed a simple model to explain and predict how the FDI probabilities change with the ratio of the field strengths in CRTC fields.

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